# emenory emenory

## 2015 Q2 Investor Conference

Aug. 13th, 2015

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#### **Outline**

- Business Model
- Review of Operations for 2Q15
- Growth Opportunity and Future Outlook
- Q & A



### **Business Model**

- Founded in 2000. First customer engaged in 2002. Achieved profitability in 2005 and IPO in 2011. The largest logic non-volatile memory IP company, 220 employees (152 R&D)\*.
- Since its IPO, the company initiated no new fund raising or bank debt, and has distributed in excess of 100% of earnings in cash dividends.
- Growth Indices: 1) No. of ongoing technology platforms
  - 2) No. of design licenses
  - 3) Royalty

Upfront Licensing Fee =Technology and Design License



Note\*: As of July 31th, 2015



#### **Worldwide Customers**



	Taiwan	China	Korea	Japan	North America	Europe	Others
Foundry	5	6	3	2	1	1	1
IDM	0	0	0	8	2	1	0
Fabless	237	351	51	36	181	94	40



























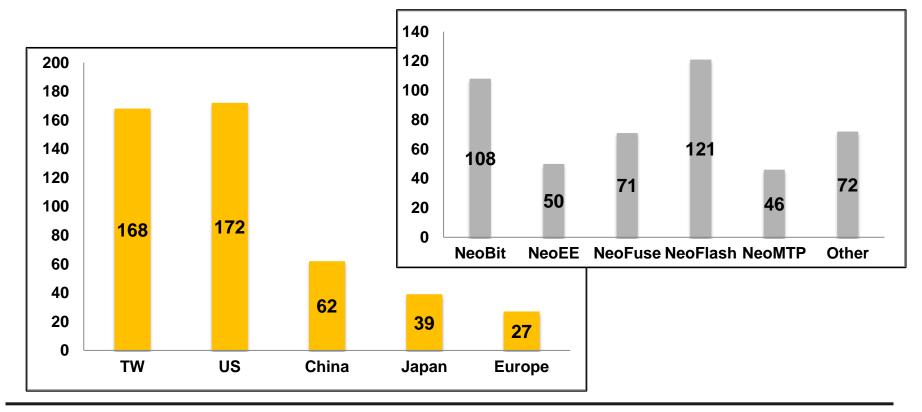






## **Patent Portfolio**

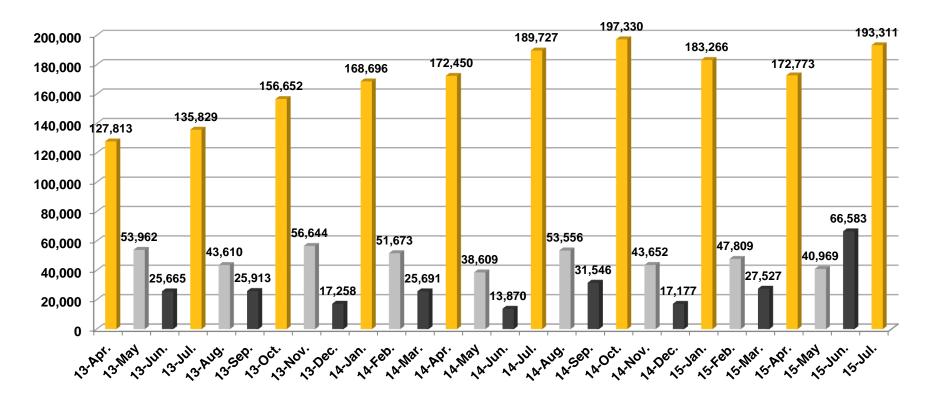
	1Q15	2Q15	Diff.
Pending	175	181	+6
Issued	278	287	+9
Total	453	468	+15



## **Quarterly Revenue Pattern\***

• The quarterly royalty from most of foundries are collected at first month of each quarter and from some other foundries are collected at second month, and none at third month.

**Unit: NTD Thousands** 



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## 2Q Revenue Breakdown

#### **Unit: NTD thousands**

	2Q15	1Q15	% change	2Q14	% change	20151H	20141H	% change
Licensing	95,982	64,056	49.84%	57,198	67.81%	160,038	132,243	21.02%
Royalty	184,343	194,546	-5.24%	167,731	9.90%	378,889	338,746	11.85%
Total	280,325	258,602	8.40%	224,929	24.63%	538,927	470,989	14.42%

#### **Unit: Number of contracts**

		2Q15	1Q15	2014	2013
Technology Licenses		8	5	21	19
Licenses	NRE	17	21	82	51
	Usage	87	82	363	342

## **Financial Income Statement**

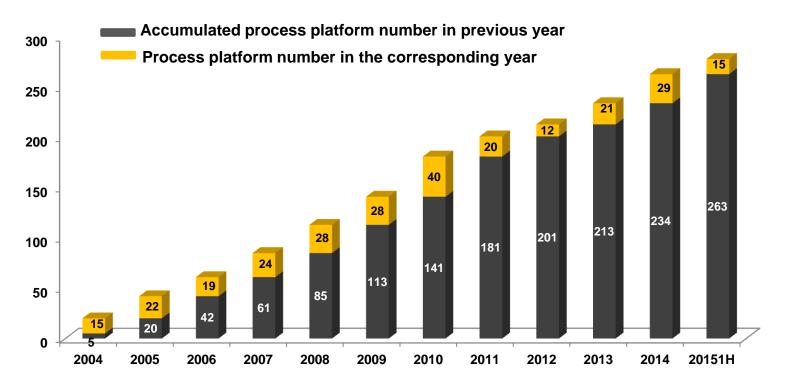
(Unit: NTD thousands)	2Q15	1Q15	% change	2Q14	% change
Revenue	280,325	258,602	8.40%	224,929	24.63%
Gross Margin	100%	100%	-	100%	-
Operating Expenses	141,435	128,976	9.66%	129,406	9.30%
Operating Margin	49.5%	50.1%	-0.6ppts	42.5%	+7.0ppts
Net Income	130,297	114,423	13.87%	82,385	58.16%
Net Margin	46.5%	44.2%	+2.3ppts	36.6%	+9.9ppts
EPS (Unit: NTD)	1.72	1.51	13.91%	1.09	57.80%
ROE	30.9%	24.8%	+6.1ppts	20.5%	+10.4ppts

## **Technology License**

**Unit: Number of contract** 

Year	2013	2014	20151H
License number	19	21	13

Note: The terms (including number of process platforms and licensing fees) for each technology license are set contractually. Payments are made according to set milestones, and there are no particular seasonal factors involved.



### **Current Technology Development Platforms**

- Total (As of Jun.) : 80\*
- 20 for NeoBit, 26 for NeoFuse, 20 for NeoEE, and
  14 for NeoMTP.

	16nm	28nm	40nm	55/65nm	80/90nm	0.11~ 0.13um	0.15~ 0.18um	>0.25 um	Total
NeoBit	•	•	ı	-	-	6	12	2	20
NeoFuse	1	7	4	8	1	3	2	-	26
NeoFlash	-	-	-	-	-	ı	ı	ı	-
NeoEE	•	-	2	-	1	6	10	1	20
NeoMTP	ı	-	1	1	2	3	7	ı	14

Note\*: 6 platforms qualified in 2Q, 8 platforms kicked off in 2Q

### **Current Technology Development Platforms**

12" Fabs	Production	Development	NVM Type	Process Type
16nm	0	1	ОТР	FF+
28nm	3	7	ОТР	LP/HPM, HLP/HPM, LPS
40nm	2	7	OTP, MTP	HV-DDI, LP
55/65nm	10	9	OTP, MTP, Flash	LP, HV-DDI, HV-OLED, DRAM, CIS
80/90nm	5	4	OTP, MTP	HV-DDI, HV-OLED, LP
0.13/0.11um	6	3	OTP, Flash	HV-DDI, BCD, Generic
0.18um	1	0	ОТР	BCD

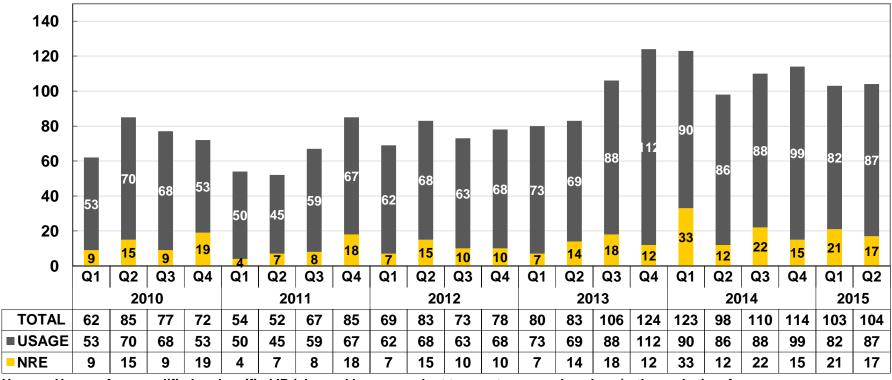
8" Fabs	Development	NVM Type	Process Type
0.13/0.11um	15	OTP, MTP, Flash	HV-DDI, BCD, LP, RF, CIS, LL
0.18/0.16/0.152um	31	OTP, MTP	Generic, LP, LL, MR, HV, Green, BCD
0.25um	2	OTP, MTP	BCD
0.35um	1	ОТР	UHV

\*As of Jun. 30, 2015



# Quarterly Design Licensing (New Tape Out)

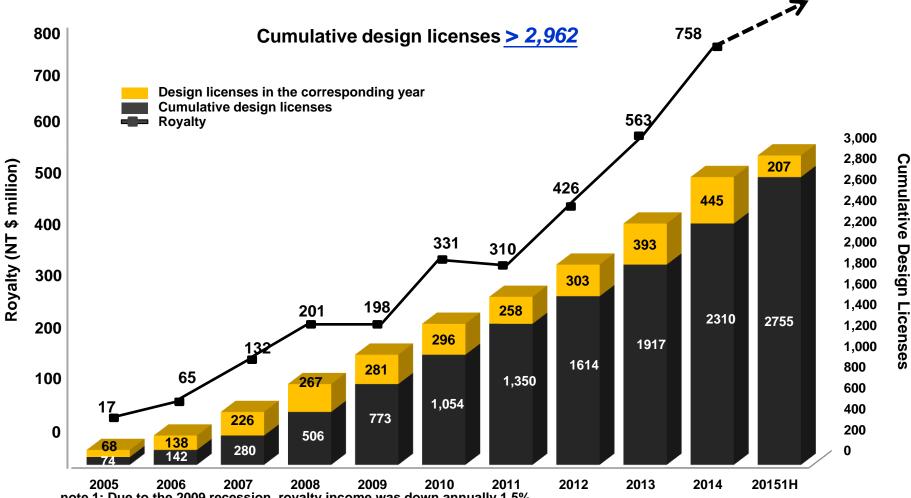
- Total 207 NTO as of 1H 2015 ( 445 @2014 393 @2013, 303 @2012, 258 @2011)



Usage: Usage of pre-qualified and verified IP (charged by per product tape out or annual package), the cycle time from design implementation to royalty payments for mass production is faster, typically less than one year.

NRE: NRE covers the customization of IP that must undergo new verification or qualification. It typically requires 1 to 1.5 years before resulting in royalty revenue.

### **Cumulative Licenses Drive Future Royalties**

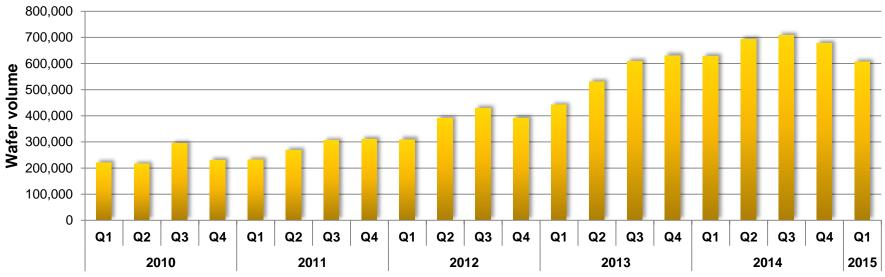


note 1: Due to the 2009 recession, royalty income was down annually 1.5%.

note 2: Pre-payment of royalty fees by a single customer contributed to 2010 annual growth of 67%, causing a drop of 6.3% in the following year, 2011.

note 3: CAGR for 2009-2013 was 30%.

### **Wafer Production Volume**



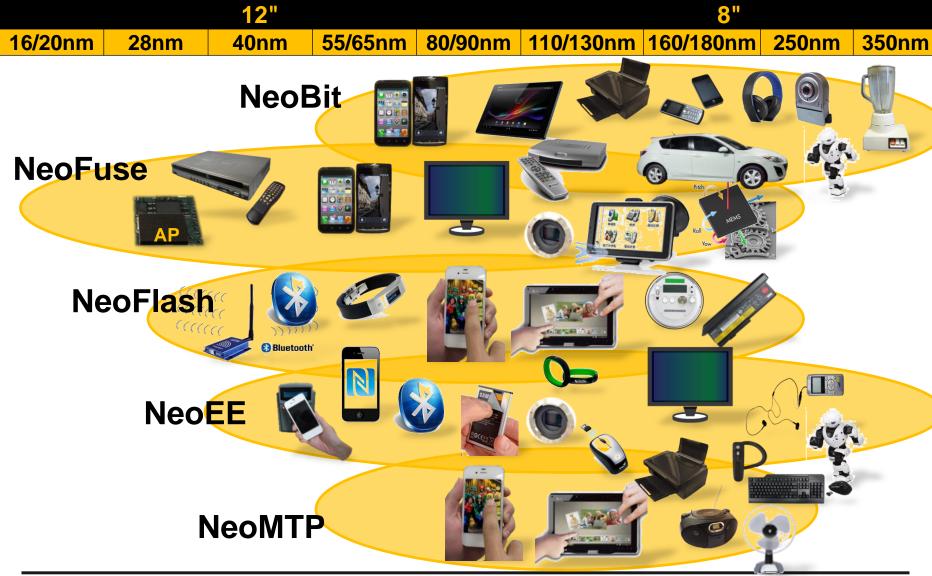
embedded eMemory IP in T Company (\$revenue); \* % of Process node in T company total revenue in 2Q15

	Process node	*% of T	2Q15	1Q15	2014	2013
8"	0.25/0.35	4%	34.4%	32.1%	30.5%	27.3%
	0.15/0.18	13%	8.9%	8%	11.9%	10.7%
	0.11/0.13	3%	17.0%	20.5%	20.8%	19.1%
12"	90nm	7%	19.2%	18.2%	16.3%	4.8%
	65nm	11%	0.4%	0.3%	0%	0%
	40/45nm	14%	0%	0%	0%	0%
	28nm	27%	0.01%	0%	0%	0%
	20nm	20%	0%	0%	0%	0%
8"		21%	14.5%	14.1%	15.6%	14.2%
12"		79%	1.8%	1.5%	1.4%	0.69%
Total		100%	4.5%	4.1%	4.5%	4.1%

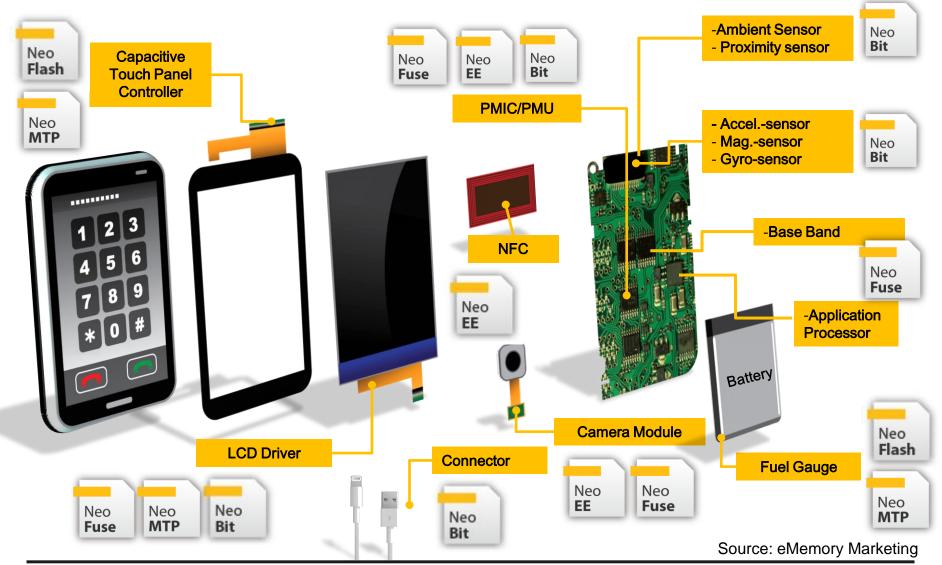
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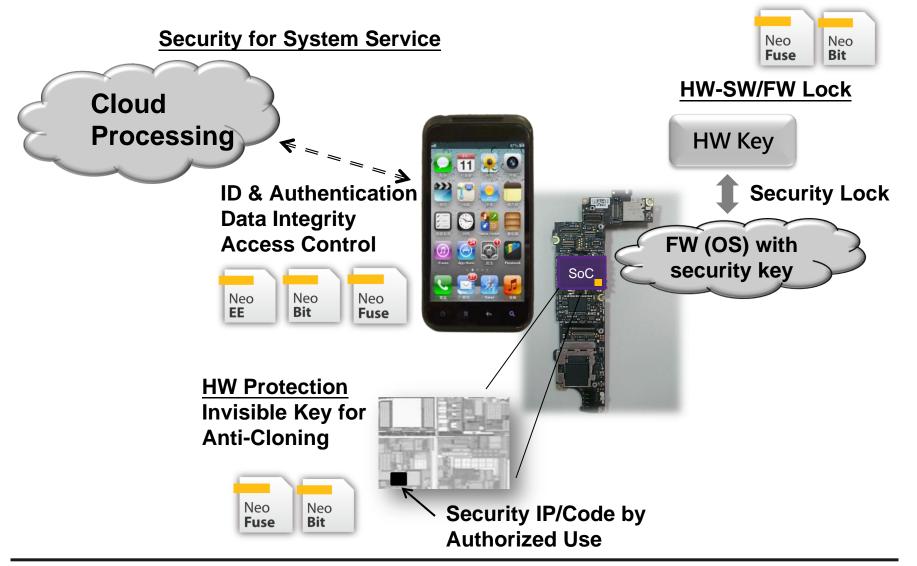
**Applications by Technology** 



## eMemory IP in Smartphone



## Security with eMemory IPs



## Benefits from Using eMemory IPs

#### **Design-in for**

- 1. Trimming
- 2. Parameter Setting
- 3. Code Storage
- 4. Identification Setting
- 5. Encryption

**NVM IP** 

#### Package/FT level

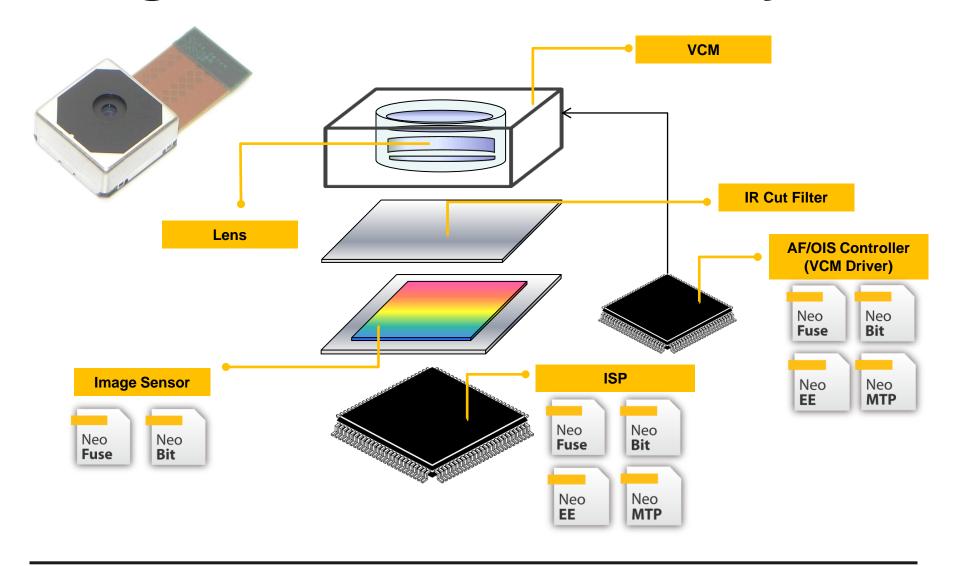
- 1. Trim: SPEC shift
- 2. Parameter Setting: cross chip optimization
- 3. Identification Setting: manufacturer resume
- 4. Function Selection : setting for target market

#### **CP Test** Package/FT **Assembling** 6. Function Selection **IC Design** CP level 1. Trim: output voltage or current 2. Parameter Setting: default value System Assembling 3. Code Storage: default F/W code

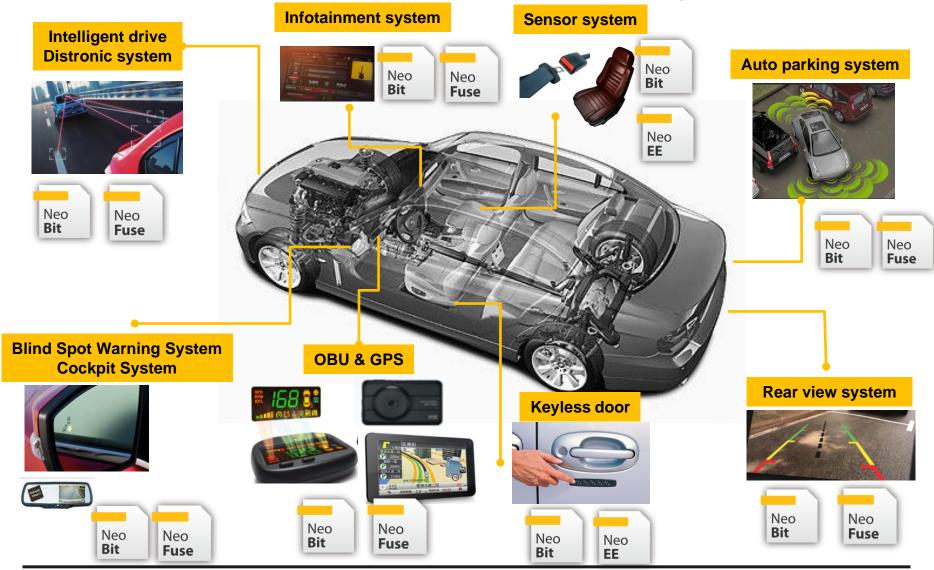
- 1. Parameter Setting: cross chip optimization
- 2. Code Storage: F/W code modification
- 3. Identification Setting: manufacturer resume
- 4. Encryption: Security algorithm or key storage

**System** 

## Imager Module with eMemory IPs



## **Autotronics with eMemory IPs**



## **Outlook for 3Q and Beyond**

- Applications in major smart phone customer continue their momentum and expand to wearable devices.
- PMICs in Chinese smart phone continue to increase production and expand to new power management applications, such as fast charger and wireless charger.
- TDDI and 55nm LCD Drivers start to ramp up.
- Applications in STB, Fingerprints, and CIS will ramp up in 2H of 2015.
- Due to security requirement and yield issue, replacement of efuse by NeoFuse is accelerating in the advanced process nodes.
- Co-work with leading foundry and European auto-electronic customers to provide automotive grade IP.

## **Key Growth Driver**

# Growth in application per mobile devices

More chip applications per smartphone/tablet product.

## **Growth into more** markets

- From consumer electronics and mobile devices to wearable devices.
- Adding new NVM product lines further enable more product applications.

# Growth in advanced technology

 Higher royalty per wafer is contributed from more advanced technology nodes.

#### **Great IoT era**

• Embedded Logic NVM will be a must.

## Q & A

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**Embedded Wisely, Embedded Widely**